10. :

NO.			
NU.			



APPROVAL SHEET

MULTILAYER CERAMIC CAPACITOR

Automotive Grade (AEC-Q200 Qualified)

Approved by customer : (signing or stamping here)	

SAMWHA CAPACITOR CO., LTD.								
Prepared by	Prepared by Checked by							
21-85	from	7/-						

2020. 04. 09.

SAMWHA CAPACITOR CO., LTD.

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< SPECIFICATION SUMMARY >									
SAMWHA Part no. CQ3216X7R106K250NRI									
Type *MLCC for Automotive Application									
Items	Specification	Unit	Test Conditions						
Capacitance	10	μF	Testing Frequency : 1 ±0.1 kHz						
Capacitance Tolerance	± 10	%	Testing Voltage : 1 ±0.2 Vrms						
Dissipation Factor	Max. 12.5	%	Should be measured at 25℃.						
Insulation Resistance	Min. 5	MΩ	Should be measured with a DC voltage not exceeding rated voltage at 25 ℃ for 2 minutes of charging.						
	3.20 ±0.30	L (mm)	Capacitance Tolerance Code page 1/9						
Chip Size	1.60 ±0.20	W (mm)	Chip size page 2/9						
	1.60 ±0.20	T (mm)	Characteristics & Test Method page 3/9~6/9						
	*Thin Lay	ver Large-Ca	apacitance Type						

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1. General Code

(1) Type Designation

CQ	<u>3216</u>	<u> X7R</u>	<u>106</u>	K	<u>250</u>	<u>N</u>	R	Ī
(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)

- 1) Multilayer Ceramic Capacitor (Automotive Grade)
- 2) Size Code:

This is expressed in tens of a millimeter.

The first two digits are the length, The last two digits are width.

3) Temperature Coefficient Code

Classification	Code	Temperature Range	Capacitance Tolerance			
Class	C0G	-55 to +125℃	±30 ppm/℃			
	X7R	-55 to +125℃	±15%			
01 11	X7S	-55 to +125℃	±22%			
Class II	X7T	-55 to +125℃	+22% ~ -33%			
	X6S	-55 to +105℃	±22%			

4) Capacitance Code(Pico farads):

The nominal Capacitance Value in pF is expressed by three digit numbers.

The first two digits represents significant figures and the last digit denotes the number of zero ex) 104 = 100000 pF

R denotes decimal

8R2 = 8.2 pF

5) Capacitance Tolerance Code

Code	Tolerance
В	± 0.1 pF
С	± 0.25 pF
D	± 0.5 pF
F	± 1.0 %

Code	Tolerance
G	± 2.0 %
J	± 5 %
K	± 10 %
M	± 20 %

6) Voltage Code

Code	6R3	100	160	250	350	500	101	201	251	501	631	102	202	302
Rated	DC	DC	DC	DC	DC	DC	DC	DC	DC	DC	DC	DC	DC	DC
Voltage	6.3V	10V	16V	25V	35V	50V	100V	200V	250V	500V	630V	1KV	2KV	3KV

7) Termination Code

N: Nickel-Tin Plate

A: Nickel-Tin Plate -> Soft Termination Type

8) Packing Code

R: 7" Reel Type, L: 13" Reel Type, B: Bulk Type

9) Thickness option

Thickne	ess (mm)	Codo	Thickne	Code	
t	Tolerance(±)	Code	t	Tolerance(±)	Code
0.50	0.05	Blank	1.35	0.20	Н
0.60	0.10	Α	1.60	0.20	I
0.80	0.10	В	1.80	0.20	J
0.85	0.15	В	2.00	0.25	K
1.00	0.15	E	2.50	0.25	L
1.10	0.15	E	2.80	0.30	М
1.15	0.15	E	3.20	0.30	Ν
1.25	0.15	E	5.00	0.40	0
1.30	0.20	E			

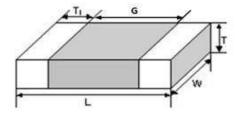
^{*3216} Size $\geq 2.2 \mu F$ 100V \Rightarrow T : Tol ± 0.30

2. Temperature Characteristics

See Page 6/9 (No.21)

3. Constructions and Dimensions

(1) Dimensions



		Dimension									
Size Code	EIA Code	Ler	ngth	Wi	dth	T4(i)	G(min.)				
		L	Tol(±)	W	Tol(±)	T1(min.)					
1005	0402	1.00	0.05	0.50	0.05	0.05	0.30				
1608	0603	1.60	0.15	0.80	0.10	0.10	0.50				
2012	0805	2.00	0.20	1.25	0.15	0.10	0.65				
3216	1206	3.20	0.30	1.60	0.20	0.15	1.00				
3225	1210	3.20	0.40	2.50	0.25	0.15	1.05				
4520	1808	4.50	0.40	2.00	0.25	0.20	1.50				
4532	1812	4.50	0.40	3.20	0.30	0.20	1.50				
5750	2220	5.70	0.50	5.00	0.40	0.30	1.85				

^{*3216} Size \geq 2.2 μ F 100V \Rightarrow L, W : Tol \pm 0.30

(Unit: mm)

(2) Construction of Termination



Specifications and Test Methods (For Automotive Applications)

No.	l est item		Spec	cification	Test Methods and Conditions			
NO.			Class I	Class II	rest Methods and Conditions			
1	Pre-and Post- Electrical Tes				-			
		Appearance Capacitance	No defects which may affect Within ±2.5% or ±0.25pF	performance Within ±10.0%				
2	High Temperature Exposure	Change Q/D.F.	(Whichever is larger) 30pF min.: Q≥1000 30pF max.: Q≥400+20×C	(*Within ±12.5%) Rated Voltage 16V min.: 0.05 max 10V: 0.075 max.	Temperature : Max. operating temperature±3 °C Maintenance Time : 1000+48/-0 hrs			
	(Storage)		C: Nominal Capacitance (pF) More than 10,000MΩ or 500Ω	*0.2 max.	Let sit for 24±2 hours at room temperature, then measure.			
		I.R.	(Whichever is smaller)					
		Appearance Capacitance	No defects which may affect	performance	Perform the 1000 cycles according to the four heat treatments listed in the following table.			
		Change	Within ±2.5% or ±0.25pF (Whichever is larger)	Within ±10.0%	Let sit for 24±2 hours at room temperature, then measure.			
3	Temperature Cycle	Q/D.F.	30pF min.:Q≥1000 30pF max.:Q≥400+20×C	Rated Voltage 16V min.: 0.05 max 10V: 0.075 max.	Step 1 2 3 4 Temp.(°C) -55+0/-3 25±2 125+3/-0 25±2			
			C: Nominal Capacitance (pF)	*0.2 max.	Time(min) 15±3 1 15±3 1			
		I.R.	More than 10,000MΩ or 500Ω (Whichever is smaller)	ĿF (*50Ω·F)	Initial measurement Perform the initial measurement according to Note 1 for Class			
4	Destructive Physical Anal	ysis	No defects or abnormalities		Per EIA-469			
		Appearance	No defects which may affect	performance	Temperature : 25~65°C, Humidity : 80~98% — Cycle Time : 24 hrs/cycle, 10 cycles			
	_ I I '	Capacitance Change	Within ±3.0% or±0.30pF (Whichever is larger)	Within ±12.5%	Let sit for 24±2 hours at room temperature, then measure. 80-98% 80-98% 80-98% RH 30-98%RH 3			
5	Moisture Resistance	Q/D.F.	30pF min.: Q≥350 10pF min. and 30pF max.: Q≥275+5/2×C 10pF max.: Q≥200+10×C C: Nominal Capacitance (pF)	Rated Voltage 16V min.: 0.05 max 10V: 0.075 max. *0.2 max.	65			
		I.R.	More than 10,000MΩ or 500Ω (Whichever is smaller)	Ð-F (*50Ω-F)	10 5 0 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24 Time (hrs)			
		Appearance	No defects which may affect	performance T				
		Capacitance Change	Within ±3.0% or ±0.30pF (Whichever is larger)	Within ±12.5%	Temperature: 85±3 °C Humidity: 80~85%			
6	Biased Humidity	Q/D.F.	30pF min.: Q≥200 30pF max.: Q≥100+10/3×C C: Nominal Capacitance (pF)	Rated Voltage 16V min.: 0.05 max 10V: 0.075 max. *0.2 max.	Maintenance Time: 1000+48/-0 hrs Let sit for 24±2 hours at room temperature, then measure.			
		I.R.	More than 1,000M Ω or 50 Ω ·F (Whichever is smaller)	(*5Ω·F)	The charge/discharge current is less than 50mA.			
		Appearance	No defects which may affect	performance	Temperature : Max. operating temperature±3 ℃			
		Capacitance Change	Within ±3.0% or ±0.30pF (Whichever is larger)	Within ±12.5%	Applied Voltage: Rated Voltage × 200% (*100%) Maintenance Time: 1000+48/-0 hrs			
7	Operational Life	Q/D.F.	30pF min.:Q≥350 10pF min. and 30pF max.: Q≥275+5/2×C 10pF max.: Q≥200+10×C C: Nominal Capacitance (pF)	Rated Voltage 16V min.: 0.05 max 10V: 0.075 max. *0.2 max.	Initial Measurement for Class II Applied 200% of the rated voltage for one hour at 125±3 °C.			
		I.R.	More than 1,000M Ω or 50 Ω ·F (Whichever is smaller)	(*5Ω·F)	Remove and let sit for 24±2 hours at room temperature, then measure.			

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Specifications and Test Methods (For Automotive Application)

Ī.,	AEC-Q200		Specif	fication		7 11 11 10 10		
No.		Item	Class	Class	s	Test Methods and Conditions		
8	External Visu	ternal Visual No defects or abnormalities		Visual inspection				
9	Physical Dime	ension	Within the specified dimensions			Using calipers		
		Appearance	No defects which may affect p	erformance				
		Capacitance Change	Within the specified tolerance					
10	Resistance to Solvents	Q/D.F.	30pF min.: Q≥1000 30pF max.: Q≥400+20×C C: Nominal Capacitance (pF)	16 10 *0.125 max.	V: 0.025 max. V: 0.03 max. V: 0.035 max. V: 0.05 max.	Per MIL-STD-202 Method 215		
		I.R.	More than 10,000MΩ or $500Ω$ ·F (Whichever is smaller)	("2005-L)				
		Appearance	No defects which may affect p	erformance				
		Capacitance Change	Within the specified tolerance			Three shocks in each direction should be applied along 3 mutually		
11	Mechanical Shock	Change Rated Voltage 50V: 0.025 max. chanical 30pF min.:Q≥1000 25V: 0.03 max.		perpendicular axes of the test specimen (18 shocks) Test Pulse Wave form: Half-sine Duration: 0.5ms Peak value: 1,500G Velocity change: 4.7m/s				
		I.R.	More than $10,000M\Omega$ or 500Ω ·F (Whichever is smaller)	(*50Ω·F)		Velocity change : 4.711/3		
		Appearance Capacitance Change	No defects or abnormalities Within the specified tolerance					
12			30pF min.:Q≥1000 30pF max.:Q≥400+20×C C: Nominal Capacitance (pF)	16 10	V: 0.025 max. V: 0.03 max. V: 0.035 max. V: 0.05 max.	The specimens should be subjected to a simple harmonic motion having a total amplitude of 1.5mm. The entire frequency range of 10 to 2,000 Hz and return to 10 Hz should be traversed in 20 minutes. This cycle should be performed 12 times in each of three mutually perpendicular directions (total of 36 times).		
		I.R.	More than 10,000M Ω or 500 Ω -F (Whichever is smaller)	*0.125 max. - (*50Ω·F)				
		Appearance	No defects which may affect p	erformance				
		Capacitance Change	Within the specified tolerance			Temperature (Eutectic solder solution) : 260±5°C		
13	Resistance to Soldering Heat	Q/D.F.	30pF min.:Q≥1000 30pF max.:Q≥400+20×C C: Nominal Capacitance (pF)	16 10	V: 0.025 max. V: 0.03 max. V: 0.035 max. V: 0.05 max.	Dipping Time: 10±1s Let sit for 24±2 hours at room temperature, then measure. Initial measurement Perform the initial measurement according to Note 1 for Class II.		
		I.R.	*0.125 max. More than 10,000MΩ or $500\Omega \cdot F$ (* $50\Omega \cdot F$) (Whichever is smaller)					
		Appearance	No defects which may affect p	erformance		Perform the 300 cycles according to the two heat treatments listed		
		Capacitance Within ±2.5% or ±0.25pF Change (Whichever is larger) Within ±15.0%		in the following table. Transfer Time : 20sec. max.				
14	Thermal Shock	Q/D.F.	30pF min.:Q≥1000 30pF max.:Q≥400+20×C C: Nominal Capacitance (pF)	16	V: 0.025 max. V: 0.03 max. V: 0.035 max. V: 0.05 max.	Let sit for 24±2 hours at room temperature, then measure. Step 1 2 Temp.(°C) -55+0/-3 125+3/-0 Time(min.) 15±3 15±3		
		I.R.	More than 10,000M Ω or 500 Ω -F (Whichever is smaller)			Initial measurement Perform the initial measurement according to Note 1 for Class II.		

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Specifications and Test Methods (For Automotive Application)

	AEC-Q200		<u> </u>	fication	,				
No.	Test		Class I	Class	II	Test Methods and Conditions			
		Appearance Capacitance	•	erformance					
15	ESD	Change Q/D.F.	30pF min.:Q≧1000 30pF max.:Q≧400+20×C C: Nominal Capacitance (pF)	16V: 10V:	0.025 max. 0.03 max. 0.035 max. 0.05 max.	Per AEC-Q200-002			
		I.R.	More than 10,000MΩ or 500Ω·F (Whichever is smaller)	*0.125 max. (*50Ω·F)					
16	Solderability		95% of the terminations is to be s	soldered evenly and o	continuously.	 (a) Preheat at 155°C for 4 hours, and then immerse the capacit in a solution of ethanol and rosin. Immerse in eutectic solder solution for 5+0/-0.5 seconds at 235±5°C. (b) Steam aging for 8 hours, and then immerse the capacitor in solution of ethanol and rosin. Immerse in eutectic solder solution for 5+0/-0.5 seconds at 235±5°C. (c) Steam aging for 8 hours, and then immerse the capacitor in solution of ethanol and rosin. Immerse in eutectic solder solution for 120±5 seconds at 260±5°C. 			
		Appearance	No defects or abnormalities			The capacitance/Q/D.F. should be measured at 25 ℃ at the			
		Capacitance Change	Within the specified tolerance			frequency and voltage shown in the table. Class Capacitance (C) Frequency Voltage C<1000pF 1±0.1MHz 0.5~5Vrms			
17	Electrical Characteriza- tion	Q/D.F.	30pF min.:Q≧1000 30pF max.:Q≧400+20×C C: Nominal Capacitance (pF)	16V:	0.025 max. 0.03 max. 0.035 max. 0.05 max.	Class I C≥1000pF 1±0.1kHz 1±0.2Vrms C≤10µF 1±0.1kHz 0.5~1.0Vrms C>10µF 120±24Hz 0.5±0.1Vrms Initial measurement Perform the initial measurement according to Note1 for Class II Measurement after test Take it out and set it for 24±2 hours (Class II) then measure			
		I.R. at 25℃	More than 100,000M Ω or 1,000 Ω ·F (Whichever is smaller)	More than 10,000M (*50Ω·F) (Whicheve		Should be measured with a DC voltage not exceeding rated			
		I.R. at 125℃	More than 10,000M Ω or 100 Ω F (Whichever is smaller)	More than 1,000MΩ (*1Ω·F) (Whichever		voltage at 25℃ and 125℃ for 2 minutes of charging.			
		Dielectric Strength	No dielectric breakdown or mecha	anical breakdown		Applied 250% of the rated voltage for 1~5 seconds The charge/discharge current is less than 50mA.			
		Appearance	No defects which may affect po	erformance		Apply a force in the direction shown in the following figure for 60±5 seconds. Support Solder Chip Printed circuit board before testing			
18	Board Flex	Capacitance Change	Within ±5.0% or ±0.5pF (Whichever is larger)	Within the specified	tolerance	Printed circuit board under test Flexure for Class I: 3mm max.			
<u> </u>		Appearance	No defects which may affect pe	lerformance		for Class II: 2mm max. Apply 18N ¹⁾ force in parallel with the test jig for 60±1 seconds.			
19	Terminal Strength	Capacitance Change		Within the specified	tolerance	¹⁾ 10N for 1608(EIA:0603) size 2N for 1005(EIA:0402) size			

Specifications and Test Methods (For Automotive Application)

Ī	AEC-	·Q200		Specif	fication		T 188 (1 1 1 2 1 2 1 2 1 2 1 2 1 2 1 2 1 2 1				
No.	Test Item		Class	Class I		Class II	Test Methods and Conditions				
			The chip endure follow	wing force.			Apply a force as shown in the following figure.				
			Chip Length	Thickne	ess (T)	Force	(i) Chip Length: 2.5mm max. (ii) Chip Length: 3.2mm min.				
1			2.5mm max.	T≤0.	5mm	8N	Beam Speed : 0.5mm/s Beam Speed : 2.5mm/s				
20	Beam Load To	est	2.5mm max.	T>0.	5mm	20N					
			3.2mm min.	T<1.2	25mm	15N	Iron Board				
ı İ		3.2mm min. T≥1		1.25	54.5N	0.6					
21	Capacitance Temperature	Capacitance Change Temperature Coefficient	0±30 ppm/°C		X7R: Within ±15% X7S: Within ±22% X6S: Within ±22% X7T: Within ±22% ~ -33%		(i) Class I The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5, the capacitance should be within the specified tolerance for the temperature coefficient. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in steps 1, 3 and 5 by the capacitance value in step 3.				
-	Characteristics Capacitance Drift						Step 1 2 3 4 5 Temp.(°C) 25±2 -55±3 25±2 125±3 25±2				
			Within ±0.2% or ±0.05 (Whichever is larger)	öpF			(ii) Class II The ranges of capacitance change compared with the 25 °C value over the temperature range from -55 °C to 125 °C. Initial measurement Perform the initial measurement according to Note 1 for Class II.				

In the case of "*" is specifications for "Thin Layer Large Capacitance Type"

Note 1. Initial Measurement for Class II

Perform a heat treatment at 150+0/-10°C for one hour, and then let sit for 24±2 hours at room temperature, then measure.

Packing

- (1) Bulk Packing
 - ① 1000 pcs per polybag
 - ② 5 polybags per inner box
 - 3 10 inner boxes per out box
- (2) Reel Packing
 - ① 8~10 reels per inner box
 - 2 6 inner boxes per out box
- (3) Reel Dimensions



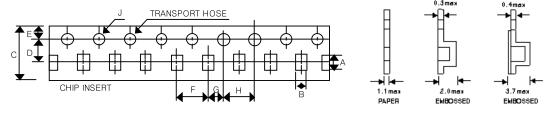


							(U	nit : mm)
Mark	Size Code	EIA Code	Α	В	С	D	Е	w
7 " Reel	1005~3225	0402~1210	Ф178 ± 2	Ф 50Min	Ф13±0.5	Ф21±0.8	2±0.5	10±1.5
7 11001	4520~4532	1808~1812	Ф180+0,-3	Ф60-0,+1	Ф13±0.2	Ф57-0+1	3±0.2	13±0.5
13 " Reel	1005~3225	0402~1210	Ф330±2	Φ 70Min	Ф13±0.5	Ф21±0.8	2±0.5	10±1.5

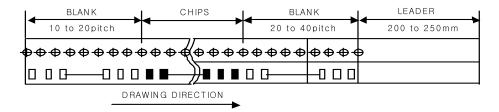
(4) Number of Package

Size Code	EIA Code	7"	13"
Size Code	EIA Code	Quantity(pcs)/Reel	Quantity(pcs)/Reel
1005	0402	10,000	50,000
1608	0603	4,000	15,000
2012	0805	3,000 ~ 4,000	8,000 ~ 15,000
3216	1206	2,000 ~ 4,000	6,000 ~ 10,000
3225	1210	1,000 ~ 3,000	4,000 ~ 10,000
4520	1808	1,500 ~ 3,000	-
4532	1812	500 ~ 1,000	1,500 ~ 5,000

(5) Tape Dimensions



Size Code	EIA Code	А	В	С	D	E	F	G	Н	J
1005	0402	1.15±0.1	0.65±0.1	8.0±0.3	3.5±0.05	1.75±0.1	2.0±0.05	2.0±0.1	4.0±0.1	1.5±0.1
1608	0603	1.9±0.2	1.10±0.2	8.0±0.3	3.5±0.05	1.75±0.1	4.0±0.1	2.0±0.1	4.0±0.1	1.5±0.1
2012	0805	2.4±0.2	1.65±0.2	8.0±0.3	3.5±0.05	1.75±0.1	4.0±0.1	2.0±0.1	4.0±0.1	1.5±0.1
3216	1206	3.6±0.2	2.00±0.2	8.0±0.3	3.5±0.05	1.75±0.1	4.0±0.1	2.0±0.1	4.0±0.1	1.5±0.1
3225	1210	3.6±0.2	2.80±0.2	8.0±0.3	3.5±0.05	1.75±0.1	4.0±0.1	2.0±0.1	4.0±0.1	1.5±0.1
4520	1808	4.8±0.2	2.3±0.2	12.0±0.3	5.5±0.1	1.75±0.1	4.0±0.1 8.0±0.1	2.0±0.1	4.0±0.1	1.5±0.1
4532	1812	4.9±0.2	3.6±0.2	12.0±0.3	5.5±0.1	1.75±0.1	8.0±0.1	2.0±0.1	4.0±0.1	1.5±0.1



Caution

▶ Storage Condition

When solderability is considered, capacitor are recommended to be used in 12 months.

(1) Temperature: 25° C ± 10° C

(2) Relative Humidity: Below 70% RH

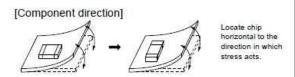
▶ The Regulation of Environmental Pollution Materials

Never use materials mentioned below in MLCC products regulated this document.

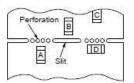
Pb, Cd, Hg, Cr⁺⁶, PBB(Polybrominated biphenyl), PBDE(Polybrominated diphenyl ethers), asbestos

► Mounting Position

Choose a mounting position that minimizes the stress imposed on the chip during flexing or bending of the board.



[Chip Mounting Close to Board Separation Point]



Chip arrangement Worst A-C- (B, D)

▶ Reflow Soldering

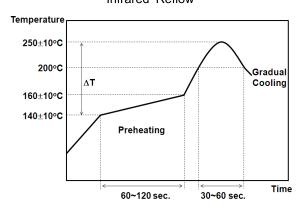
- The sudden temperature change easily causes mechanical damages to ceramic components. Therefore, the preheating procedures should be required for the soldering of ceramic components.
- 2. Please refer to the recommended soldering profiles as shown in figures, and keep the temperature difference($\triangle T$) within the range recommended in Table 1.

Table 1

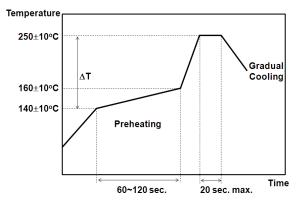
Size code (EIA Code)	Temperature Difference
1005~3216 (0402~1206)	∆T≤190℃
3225 (1210)	△T≤130℃

Recommended Reflow Soldering Profile for Lead Free Solder

Infrared Reflow



Vapor Reflow



Note

► 'Aging'/'De-aging' behavior of high dielectric constant type MLCCs (Typically represented by X7R temperature characteristic of which main composition is BaTiO₃)

'Aging' / 'De-aging' Behavior of high dielectric MLCCs Please note that high dielectric type dielectric ceramic capacitors have a "normal" 'aging' behavior / characteristic, that is; their capacitance value decreases with time from its value when it was first manufactured. From that date, the capacitance value begins to decrease at a logarithmic rate defined by:

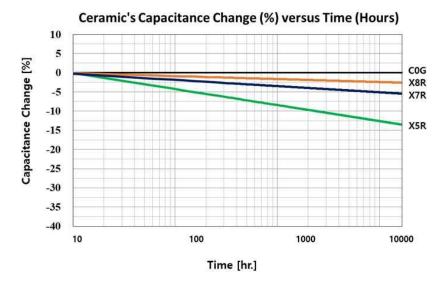
$$C_t = C_{24} (1 - k log 10 t)$$

where,

 C_t : Capacitance value, t hours after the start of 'aging' C_{24} : Capacitance value, 24 hours after its manufacture

k : Aging constant (capacitance decrease per decade-hour)

t : time, in hours, from the start of 'aging'



The capacitance value can be restored (also known as 'de-aged') by exposing the component to elevated temperatures approaching its curie temperature (approximately $120\,^{\circ}$ C). This 'de-aging' can occur during the component's solder-assembly onto the PCB, during life or temperature cycle testing, or by baking at $150\,^{\circ}$ C for about 1 hour.